LOW VOLTAGE (1.24V) ADJUSTABLE PRECISION SHUNT REGULATOR AZ431L

General Description

The AZ431L series ICs are low voltage three-terminal adjustable regulators with guaranteed thermal stability over a full operation range. These ICs feature sharp turn-on characteristics, low temperature coefficient and low output impedance, which make them ideal substitutes for Zener diodes in applications such as switching power supply, charger, motherboard and other adjustable regulators.

The output voltage can be set to any value between 1.24V and 18V with two external resistors.

The AZ431L precision reference is offered in two voltage tolerance: 0.5% and 1.0%.

These ICs are available in 4 packages: TO-92 (bulk or ammo packing), SOT-23, SOT-23-5 and SOT-89.

Features

- Wide Programmable Precise Output Voltage from 1.24V to 18V
- High Stability under Capacitive Load
- Low Temperature Deviation: 3mV Typical
- Low Equivalent Full-range Temperature Coefficient: 20PPM/^{o}C Typical
- Low Dynamic Output Resistance: 0.05Ω Typical
- High Sink Current Capacity from 0.1mA to 100mA
- Low Output Noise
- Wide Operating Range of -40 to 125^{o}C

Applications

- Graphic Card
- PC Motherboard
- Voltage Adapter
- Switching Power Supply
- Charger

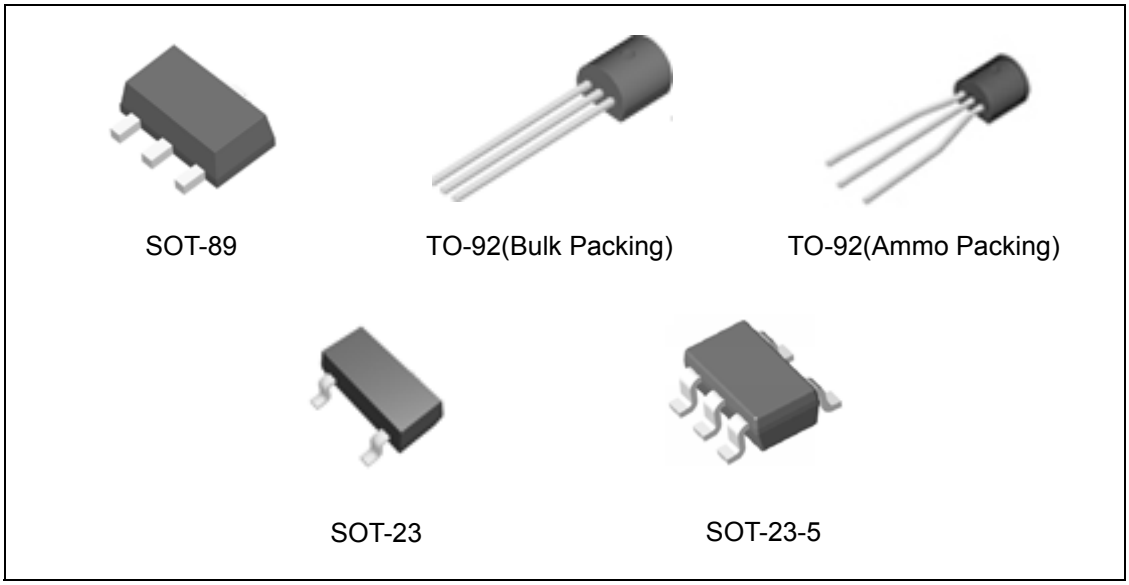
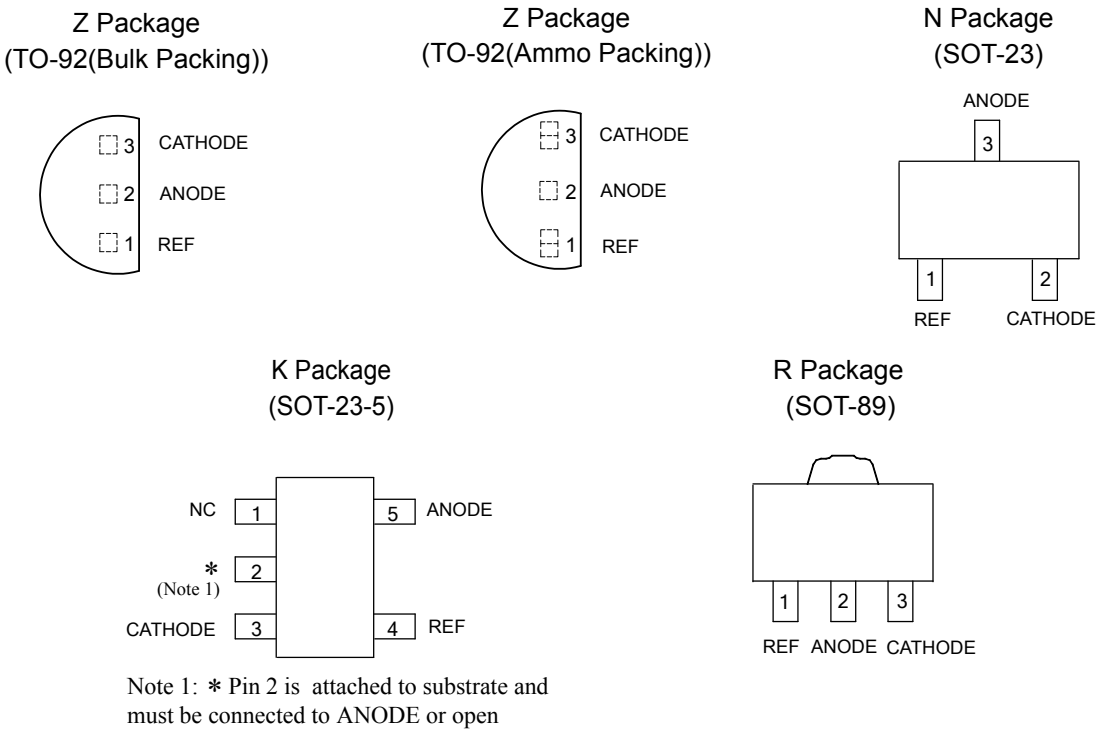


Figure 1. Package Types of AZ431L

Pin Configuration



Note 1: * Pin 2 is attached to substrate and must be connected to ANODE or open

Figure 2. Pin Configuration of AZ431L (Top View)

Functional Block Diagram

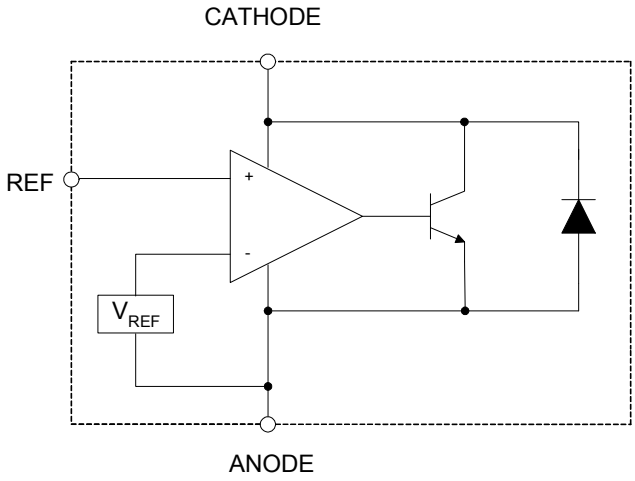
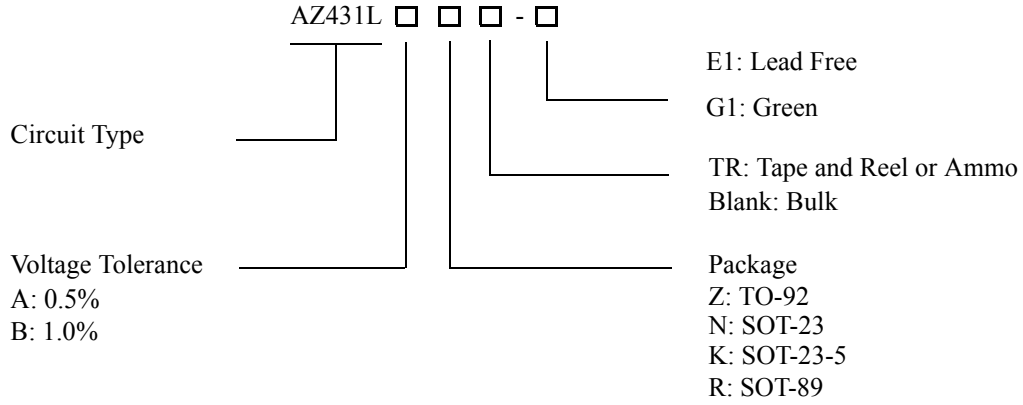


Figure 3. Functional Block Diagram of AZ431L

Ordering Information



Package	Temperature Range	Voltage Tolerance	Part Number		Marking ID		Packing Type
			Lead Free	Green	Lead Free	Green	
TO-92	-40 to 125°C	0.5%	AZ431LAZ-E1	AZ431LAZ-G1	AZ431LAZ-E1	AZ431LAZ-G1	Bulk
		0.5%	AZ431LAZTR-E1	AZ431LAZTR-G1	AZ431LAZ-E1	AZ431LAZ-G1	Ammo
		1.0%	AZ431LBZ-E1	AZ431LBZ-G1	AZ431LBZ-E1	AZ431LBZ-G1	Bulk
		1.0%	AZ431LBZTR-E1	AZ431LBZTR-G1	AZ431LBZ-E1	AZ431LBZ-G1	Ammo
SOT-23	-40 to 125°C	0.5%	AZ431LANTR-E1	AZ431LANTR-G1	EA6	GA6	Tape & Reel
		1.0%	AZ431LBNTR-E1	AZ431LBNTR-G1	EA7	GA7	Tape & Reel
SOT-23-5	-40 to 125°C	0.5%	AZ431LAKTR-E1	AZ431LAKTR-G1	E5A	G5A	Tape & Reel
		1.0%	AZ431LBKTR-E1	AZ431LBKTR-G1	E6A	G6A	Tape & Reel
SOT-89	-40 to 125°C	0.5%	AZ431LARTR-E1	AZ431LARTR-G1	E41A	G41A	Tape & Reel
		1.0%	AZ431LBRTR-E1	AZ431LBRTR-G1	E41B	G41B	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

Absolute Maximum Ratings (Note 2)

Parameter	Symbol	Value		Unit
Cathode Voltage	V_{KA}	20		V
Cathode Current Range (Continuous)	I_{KA}	-100 to 100		mA
Reference Input Current Range	I_{REF}	10		mA
Power Dissipation	P_D	Z, R Package	770	mW
		N, K Package	370	
Junction Temperature	T_J	150		°C
Storage Temperature Range	T_{STG}	-65 to 150		°C

Note 2: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only , and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Cathode Voltage	V_{KA}	V_{REF}	18	V
Cathode Current	I_{KA}	0.1	100	mA
Operating Ambient Temperature Range		-40	125	°C

Electrical Characteristics

(Operating Conditions: T_A=25°C, unless otherwise noted.)

Parameter		Test Circuit	Symbol	Conditions		Min	Typ	Max	Unit
Reference Voltage	0.5%	4	V_{REF}	$V_{KA}=V_{REF}$, I_{KA}=10mA		1.234	1.240	1.246	V
	1.0%					1.228	1.240	1.252	
Deviation of Reference Voltage Over Full Temperature Range		4	ΔV_{REF}	$V_{KA}=V_{REF}$ I_{KA}=10mA	0°C to 70°C		2	10	mV
					-40°C to 85°C		3	10	
					-40°C to 125°C		4	15	
Ratio of Change in V_{REF} to the Change in Cathode Voltage		5	$\frac{\Delta V_{REF}}{\Delta V_{KA}}$	I_{KA}=10mA, ΔV_{KA}:V_{REF} to 16V			-0.5	-1.5	mV/V
Reference Input Current		5	I_{REF}	I_{KA}=10mA, R1=10KΩ, R2=∞			0.15	0.4	μA
Deviation of Reference Current Over Full Temperature Range		5	ΔI_{REF}	I_{KA}=10mA, R1=10KΩ, R2=∞ T_A=-40 to 125°C			0.1	0.4	μA
Minimum Cathode Current for Regulation		4	I_{KA} (Min)	$V_{KA}=V_{REF}$			55	80	μA
Off-state Cathode Current		6	I_{KA} (Off)	V_{REF}=0, V_{KA}=18V			0.04	0.10	μA
				V_{KA}=6, V_{REF}=0			0.01	0.05	
Dynamic Impedance		4	Z_{KA}	$V_{KA}=V_{REF}$, I_{KA}=1 to 100mA f≤ 1.0kHz			0.05	0.15	Ω
Thermal Resistance			θ_{JC}	SOT-23			84.84		°C/W
				SOT-23-5			84.84		
				TO-92			140.80		
				SOT-89			29.80		

Electrical Characteristics (Continued)

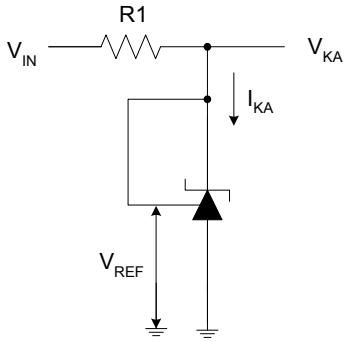


Figure 4. Test Circuit 4 for $V_{KA}=V_{REF}$

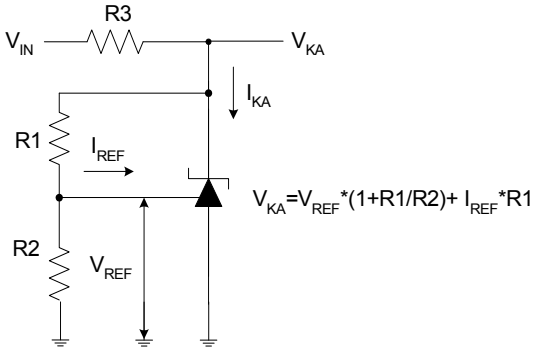


Figure 5. Test Circuit 5 for $V_{KA}>V_{REF}$

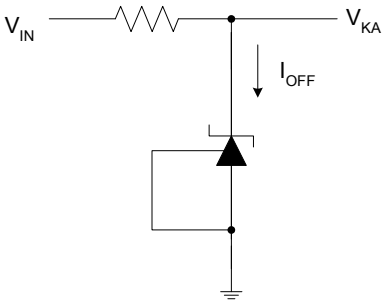


Figure 6. Test Circuit 6 for I_{OFF}

Typical Performance Characteristics

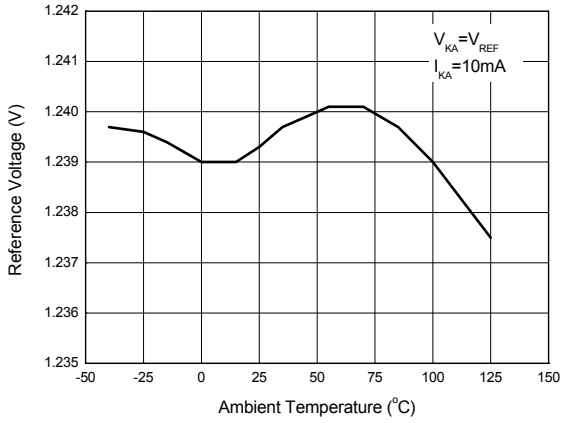


Figure 7. Reference Voltage vs. Ambient Temperature

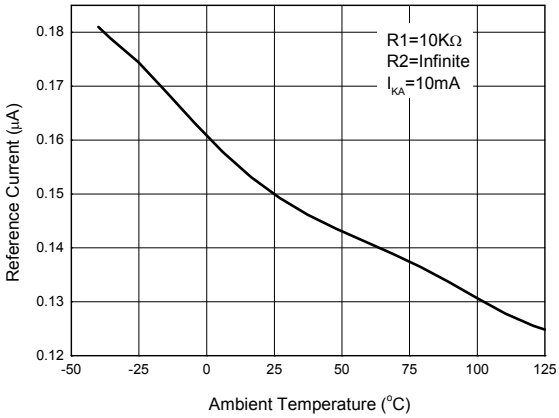


Figure 8. Reference Current vs. Ambient Temperature

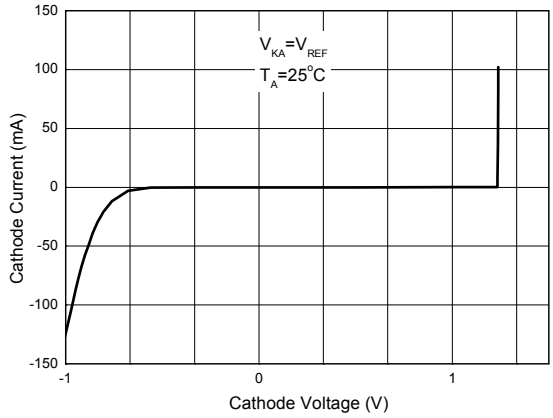


Figure 9. Cathode Current vs. Cathode Voltage

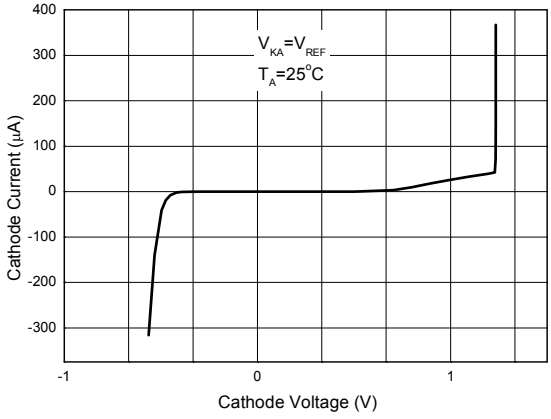


Figure 10. Cathode Current vs. Cathode Voltage

Typical Performance Characteristics (Continued)

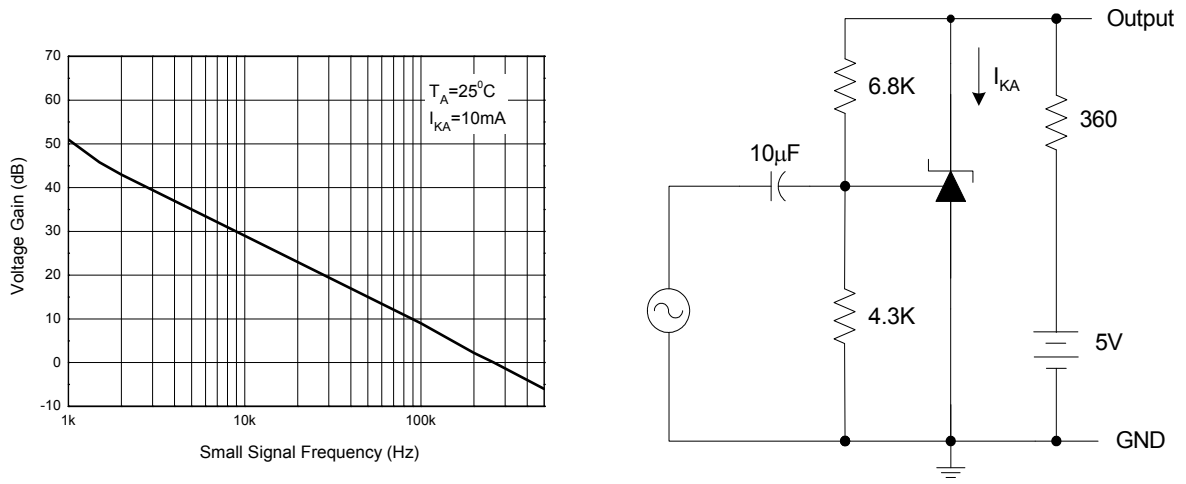


Figure 11. Small Signal Voltage Gain vs. Frequency

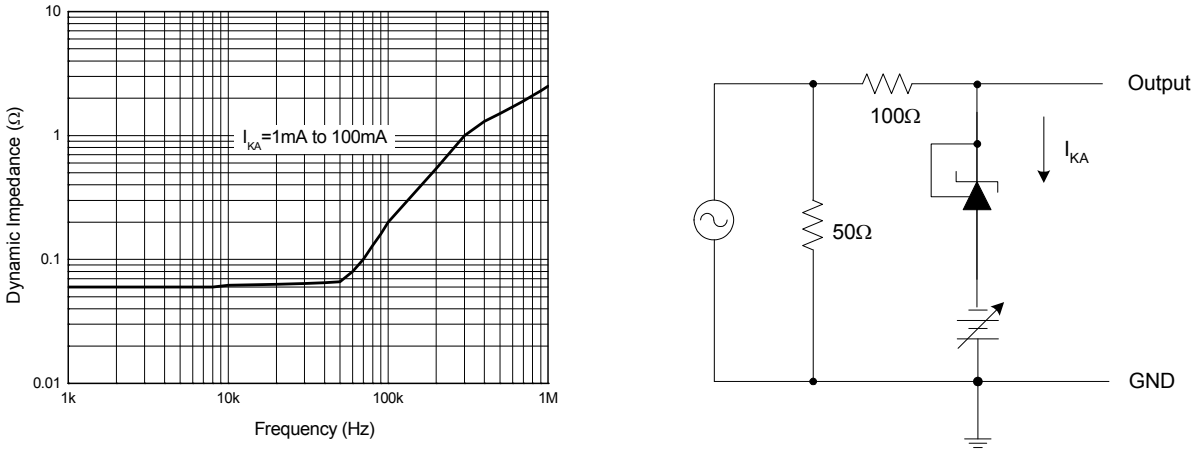


Figure 12. Dynamic Impedance vs. Frequency

Typical Performance Characteristics (Continued)

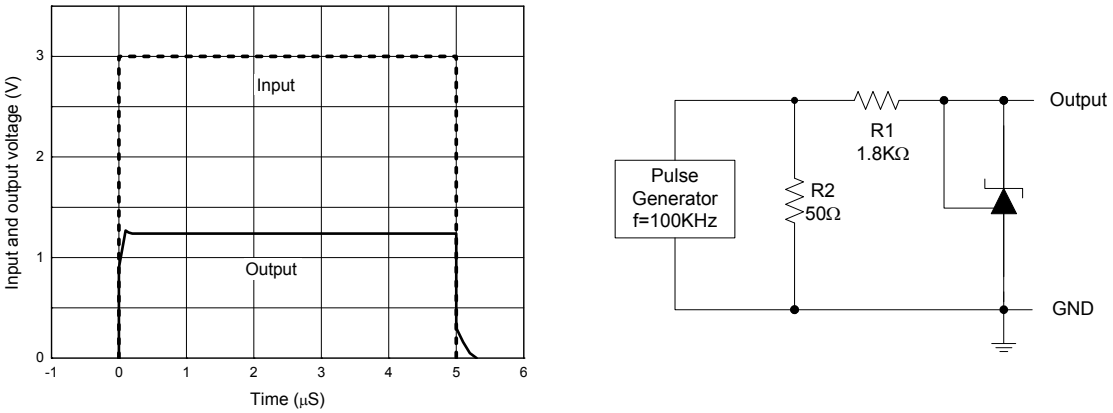


Figure 13. Pulse Response of Input and Output Voltage

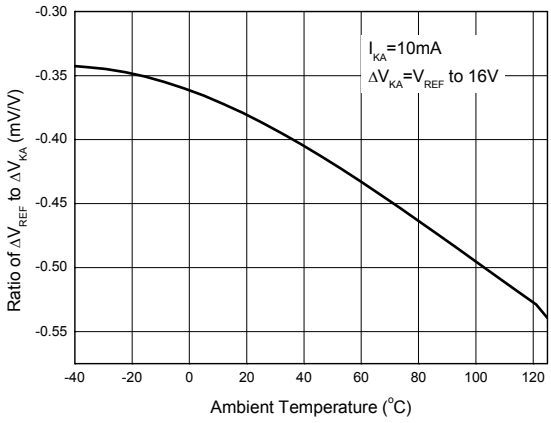


Figure 14. Ratio of Delta Reference Voltage to the Ratio of Cathode Voltage vs. Ambient Temperature

Typical Applications

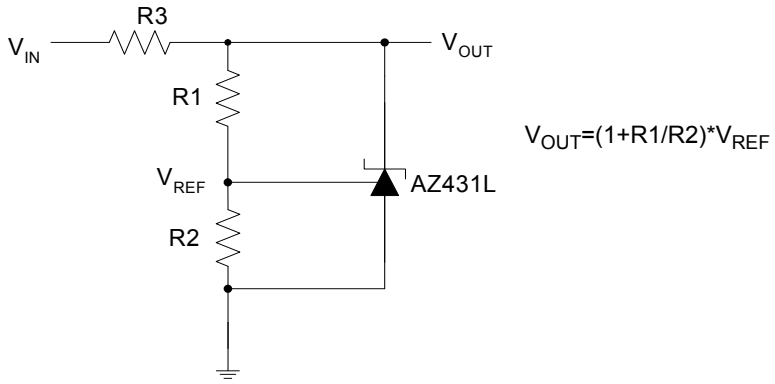


Figure 15. Shunt Regulator

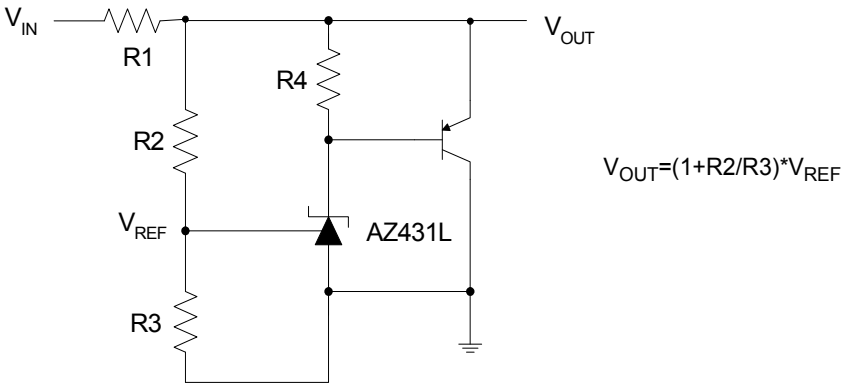


Figure 16. High Current Shunt Regulator

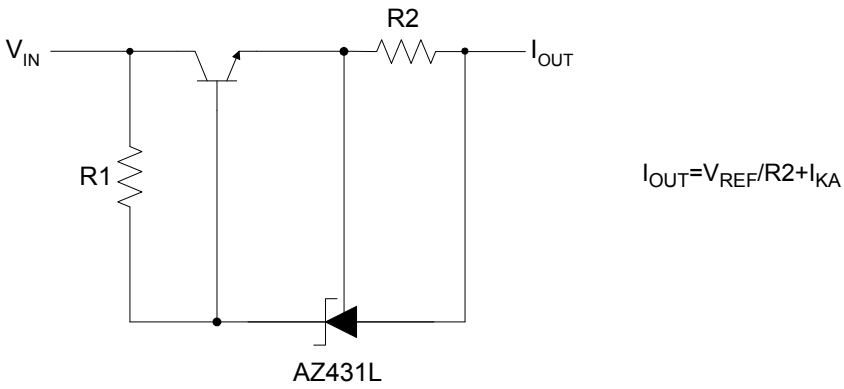


Figure17. Current Source or Current Limit

Typical Application (Continued)

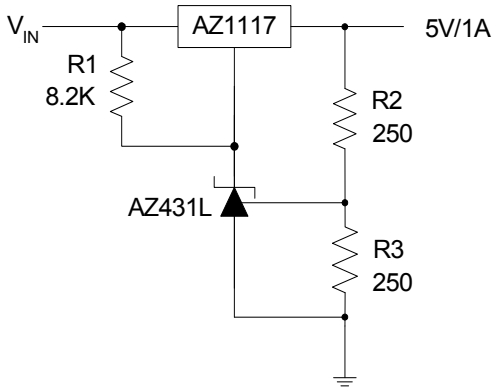


Figure18. Precision 5V 1A Regulator

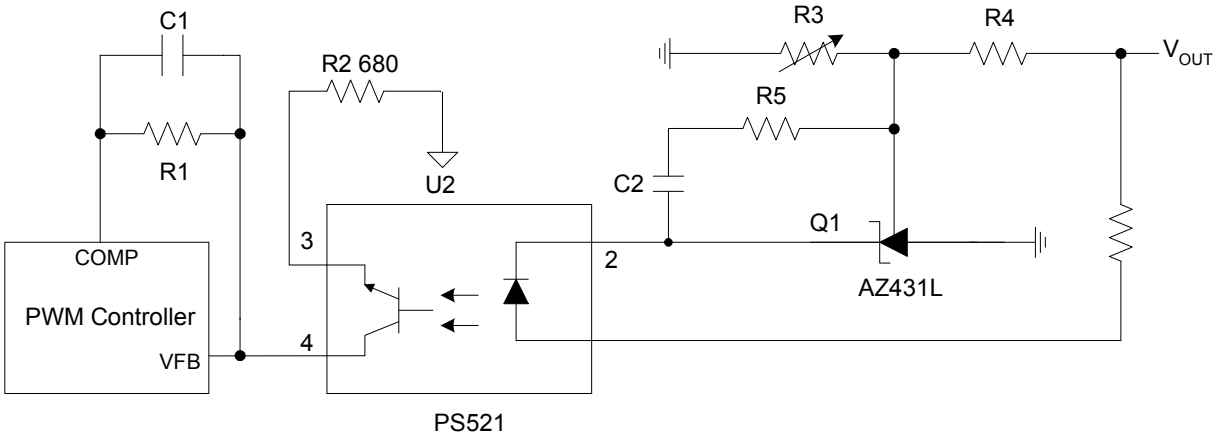
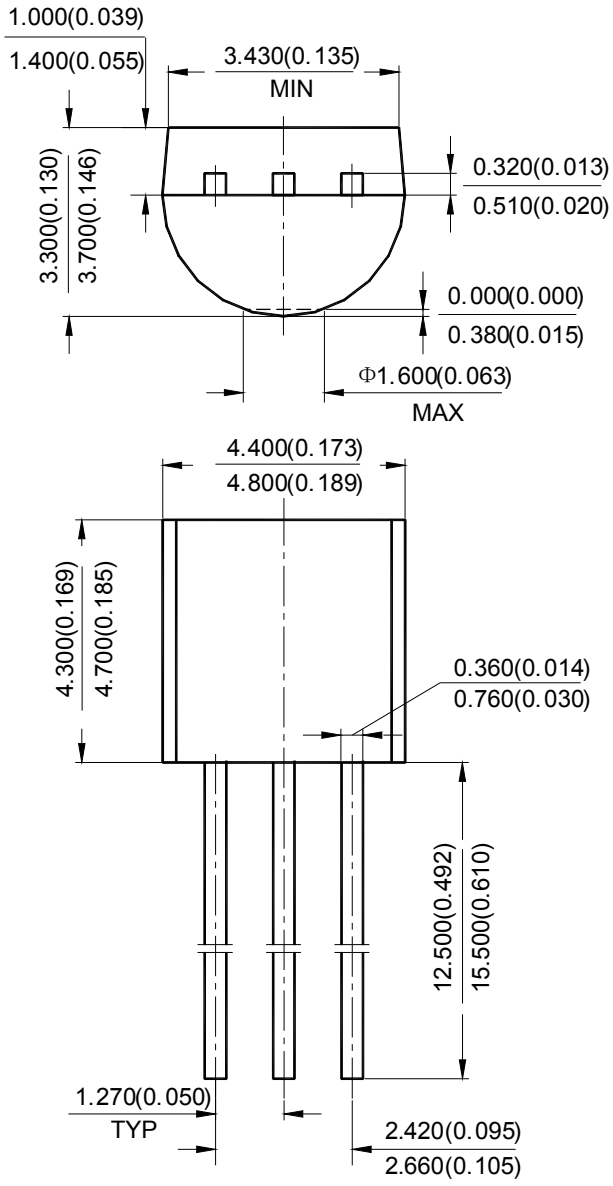


Figure 19. PWM Converter with Reference

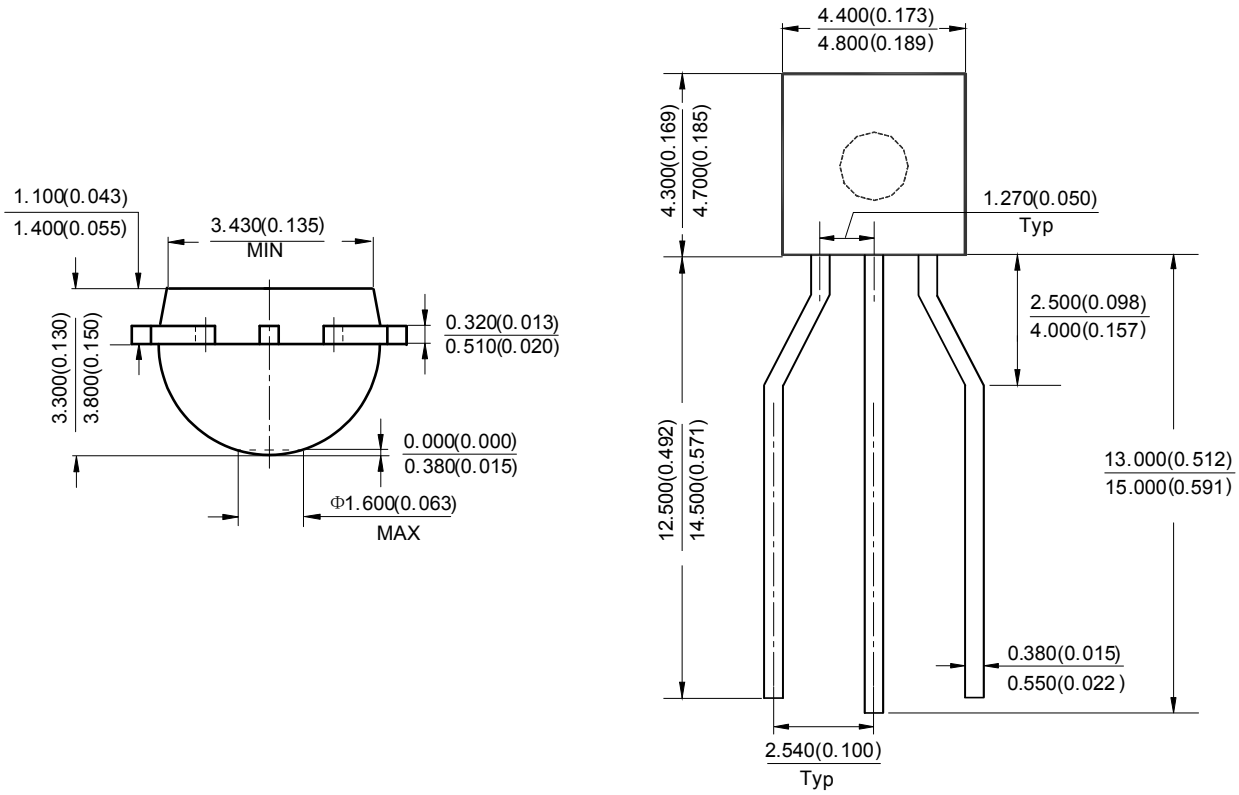
Mechanical Dimensions

TO-92(Bulk Packing) **Unit: mm(inch)**



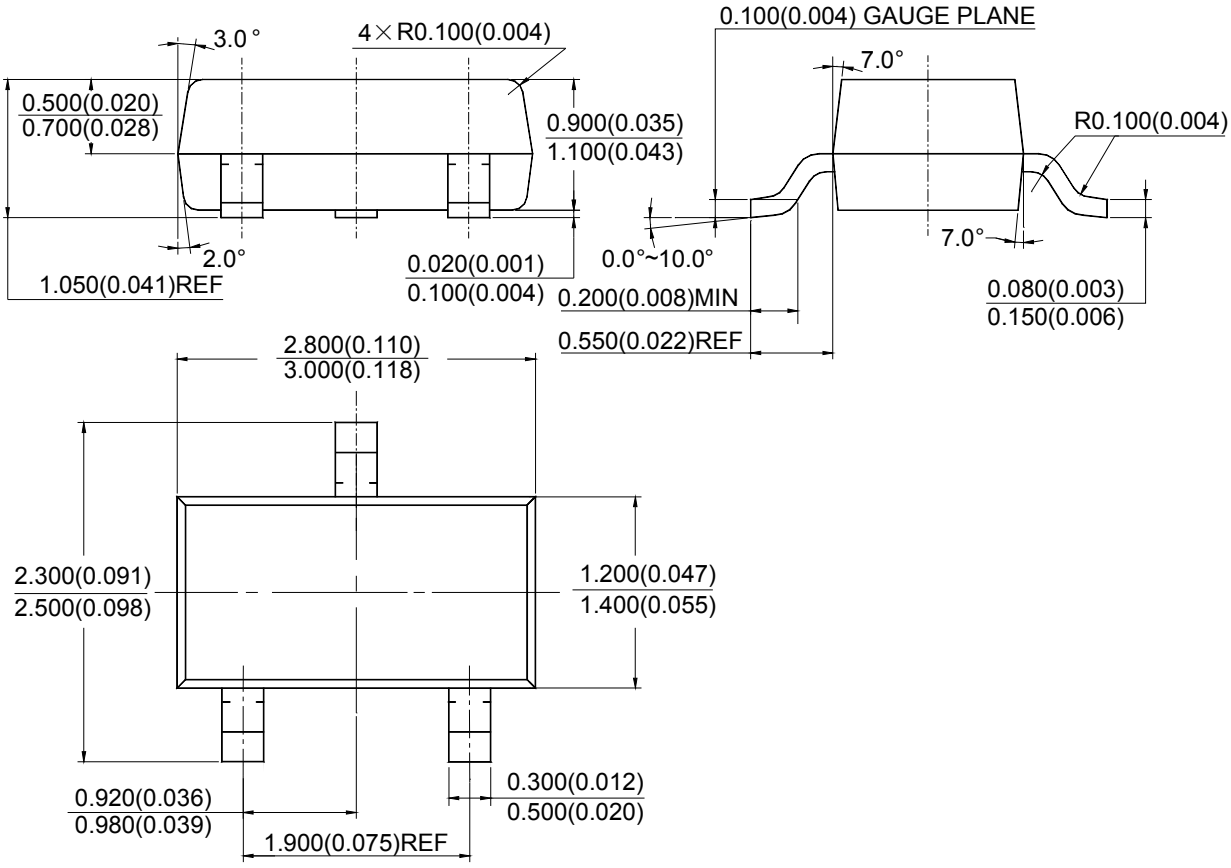
Mechanical Dimensions (Continued)

TO-92(Ammo Packing) **Unit: mm(inch)**



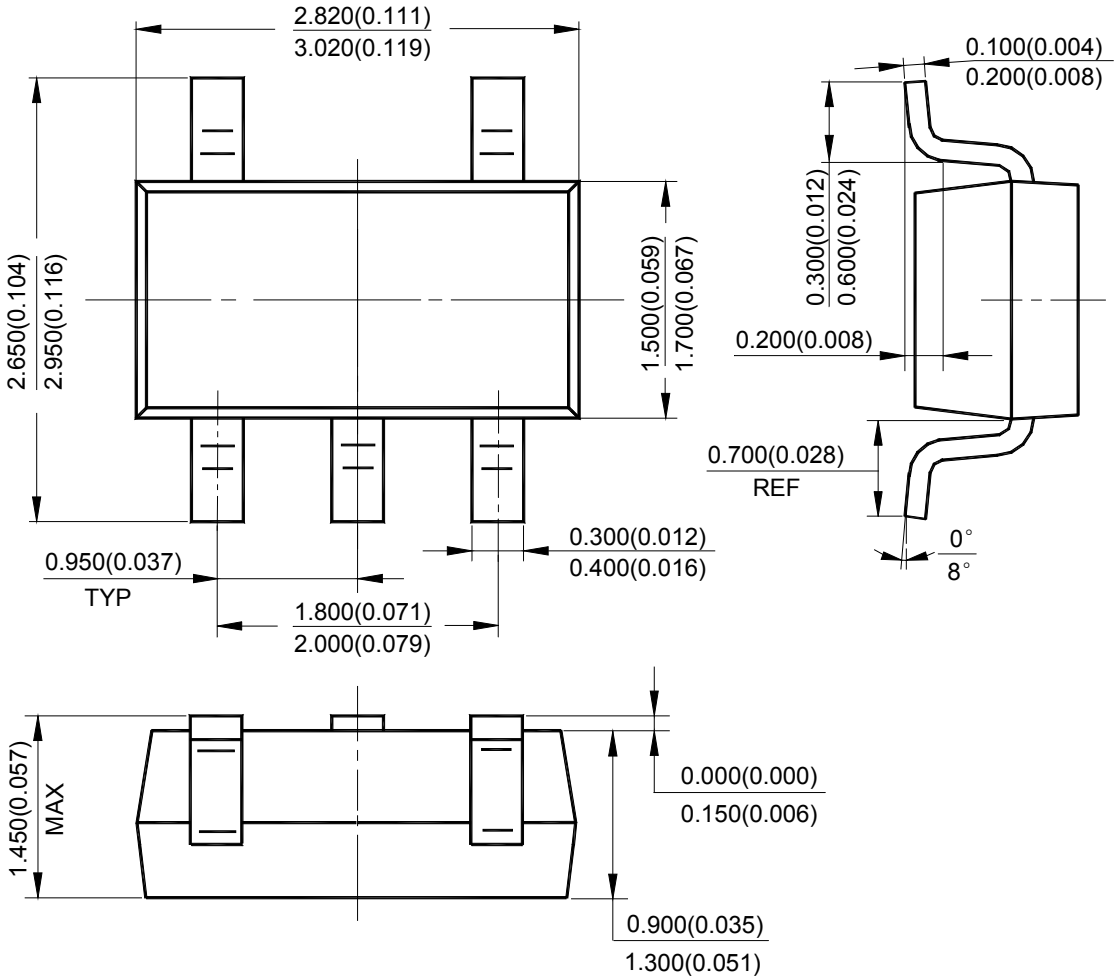
Mechanical Dimensions (Continued)

SOT-23 **Unit: mm(inch)**



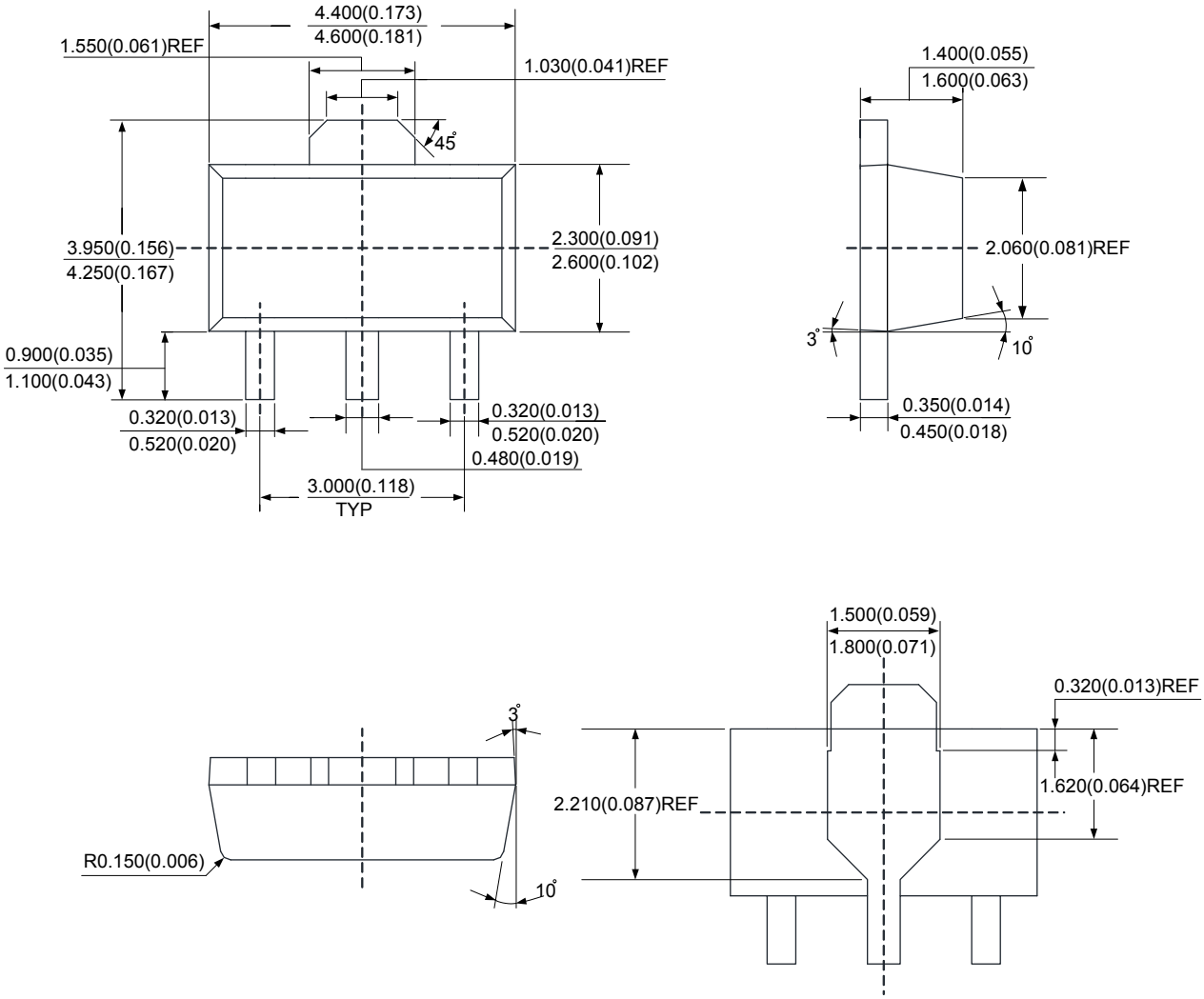
Mechanical Dimensions (Continued)

SOT-23-5 **Unit: mm(inch)**



Mechanical Dimensions (Continued)

SOT-89 **Unit: mm(inch)**



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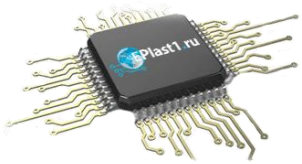
Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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